

NPN Silicon Germanium RF Transistor

Target data sheet

- High gain ultra low noise RF transistor for low current operation
- Provides outstanding performance for a wide range of wireless applications up to 10 GHz and more
- Optimum gain and noise figure at low current operation
- Ideal for WLAN applications
- Outstanding noise figure F = 0.5 dB at 1.8 GHz
 Outstanding noise figure F = 0.8 dB at 6 GHz
- High maximum stable and available gain $G_{\rm ms}$ = 24 dB at 1.8 GHz, $G_{\rm ma}$ = 16.5 dB at 6 GHz
- 150 GHz f_T-Silicon Germanium technology
- Extremly small and flat leadless package height 0.32 mm max.
- Pb-free (RoHS compliant) package
- Qualified according AEC Q101

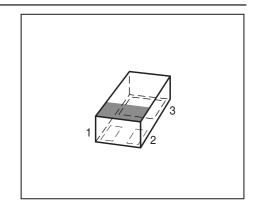




ESD (Electrostatic discharge) sensitive device, observe handling precaution!

Туре	Marking	Pin Configuration			Package	
BFR720L3RH	R3	1 = B	2 = C	3 = E	TSLP-3-9	

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2008-07-04

K/W

 \leq tbd



Maximum Ratings

Junction - soldering point²⁾

Parameter	Symbol	Value	Unit
Collector-emitter voltage	V_{CEO}		V
<i>T</i> _A > 0 °C		4	
<i>T</i> _A ≤ 0 °C		3.5	
Collector-emitter voltage	V_{CES}	13	
Collector-base voltage	V_{CBO}	13	
Emitter-base voltage	V_{EBO}	1.2	
Collector current	I _C	20	mA
Base current	I _B	2	
Total power dissipation ¹⁾	P _{tot}	80	mW
$T_{S} \le tbd$			
Operating junction temperature range	T _{io}	-65 150	°C
Storage junction temperature range	T _{istg}	-65 150	
Thermal Resistance			
Parameter	Symbol	Value	Unit

 R_{thJS}

Electrical Characteristics at $T_A = 25$ °C, unless otherwise specified

Parameter	Symbol	Values			Unit
		min.	typ.	max.	
DC Characteristics					
Collector-emitter breakdown voltage	V _{(BR)CEO}	4	4.7	-	V
$I_{\rm C}$ = 1 mA, $I_{\rm B}$ = 0					
Collector-emitter cutoff current	I _{CES}	-	_	30	μΑ
$V_{CE} = 13 \text{ V}, V_{BE} = 0$					
Collector-base cutoff current	I _{CBO}	-	-	100	nA
$V_{\rm CB} = 5 \text{ V}, I_{\rm E} = 0$					
Emitter-base cutoff current	I _{EBO}	-	-	2	μA
$V_{\rm EB} = 0.5 \text{V}, I_{\rm C} = 0$					
DC current gain-	h _{FE}	160	250	400	-
$I_{\rm C}$ = 13 mA, $V_{\rm CE}$ = 3 V, pulse measured					

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 $^{^{1}}T_{\mbox{\scriptsize S}}$ is measured on the collector lead at the soldering point to the pcb

 $^{^2\}mbox{For calculation of}\,R_{\mbox{\scriptsize thJA}}$ please refer to Application Note Thermal Resistance



Electrical Characteristics at $T_A = 25^{\circ}$ C, unless otherwise specified

Electrical Characteristics at $T_A = 25^{\circ}C$, unless Parameter	Symbol		Values		
		min.	typ.	max.	
AC Characteristics (verified by random sampling	ı)	1	ı	ı	1
Transition frequency	f_{T}	-	45	-	GHz
$I_{\rm C}$ = 13 mA, $V_{\rm CE}$ = 3 V, f = 1 GHz					
Collector-base capacitance	C _{cb}	-	0.07	-	pF
$V_{\text{CB}} = 3 \text{ V}, f = 1 \text{ MHz}, V_{\text{BE}} = 0 ,$					
emitter grounded					
Collector emitter capacitance	C _{ce}	-	0.26	-	
$V_{CE} = 3 \text{ V}, f = 1 \text{ MHz}, V_{BE} = 0$,					
based grounded					
Emitter-base capacitance	C _{eb}	-	0.27	-	
$V_{\text{EB}} = 0.5 \text{ V}, f = 1 \text{ MHz}, V_{\text{CB}} = 0$,					
collector grounded					
Noise figure	NF				dB
$I_{\rm C}$ = 5 mA, $V_{\rm CE}$ = 3 V, f = 1.8 GHz, $Z_{\rm S}$ = $Z_{\rm Sopt}$		-	0.5	-	
$I_{\rm C}$ = 5 mA, $V_{\rm CE}$ = 3 V, f = 6 GHz, $Z_{\rm S}$ = $Z_{\rm Sopt}$		-	0.8	-	
Power gain ¹⁾	G _{ms}	-	24	-	dB
$I_{\rm C}$ = 13 mA, $V_{\rm CE}$ = 3 V, $Z_{\rm S}$ = $Z_{\rm Sopt}$,					
$Z_{L} = Z_{Lopt}$, $f = 1.8 \text{ GHz}$					
Power gain, maximum available ¹⁾	G _{ma}	-	16.5	-	dB
$I_{\rm C}$ = 13 mA, $V_{\rm CE}$ = 3 V, $Z_{\rm S}$ = $Z_{\rm Sopt}$,					
$Z_{L} = Z_{Lopt}, f = 6 \text{ GHz}$					
Transducer gain	$ S_{21e} ^2$				dB
$I_{\rm C}$ = 13 mA, $V_{\rm CE}$ = 3 V, $Z_{\rm S}$ = $Z_{\rm L}$ = 50 Ω ,					
f = 1.8 GHz		-	22	-	
f = 6 GHz		-	13.5	-	
Third order intercept point at output ²⁾	IP ₃	-	20.5	-	dBm
$V_{\text{CE}} = 3 \text{ V}, I_{\text{C}} = 10 \text{ mA}, Z_{\text{S}} = Z_{\text{L}} = 50 \Omega, f = 1.8 \text{ GHz}$					
1dB Compression point	P _{-1dB}	-	6	-	
$I_{\rm C}$ = 13 mA, $V_{\rm CE}$ = 3 V, $Z_{\rm S}$ = $Z_{\rm L}$ =50 Ω , f = 1.8 GHz					

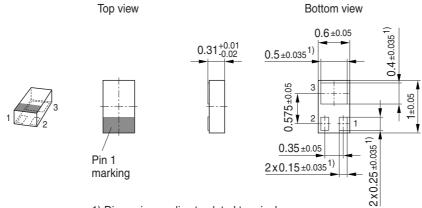
 $^{^{1}}G_{\text{ma}} = |S_{21e} / S_{12e}| (k-(k^{2}-1)^{1/2}), G_{\text{ms}} = |S_{21e} / S_{12e}|$

²IP3 value depends on termination of all intermodulation frequency components.

Termination used for this measurement is $50\,\Omega$ from 0.1 MHz to 6 GHz



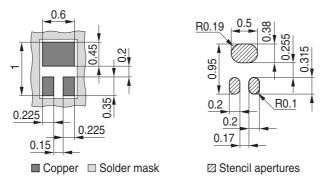
Package Outline



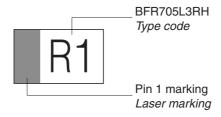
1) Dimension applies to plated terminal

Foot Print

For board assembly information please refer to Infineon website "Packages"

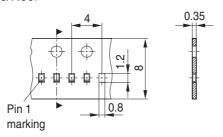


Marking Layout (Example)



Standard Packing

Reel ø180 mm = 15.000 Pieces/Reel



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